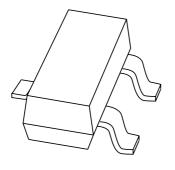
DISCRETE SEMICONDUCTORS

DATA SHEET



BAT721 seriesSchottky barrier (double) diodes

Product specification Supersedes data of 1999 May 06 2001 Oct 12





Schottky barrier (double) diodes

BAT721 series

FEATURES

- · Ultra high switching speed
- · Low forward voltage
- · Guard ring protected
- Small plastic SMD package.

APPLICATIONS

- Ultra high-speed switching
- · Voltage clamping
- · Protection circuits.

DESCRIPTION

Planar Schottky barrier diodes encapsulated in a SOT23 small plastic SMD package. Single diodes and double diodes with different pinning are available.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
BAT721	L7*
BAT721A	L8*
BAT721C	L9*
BAT721S	L0*

Note

- 1. * = p: Made in Hong Kong.
 - * = t : Made in Malaysia.
 - * = W: Made in China.

PINNING

PIN	BAT721						
FIN		Α	С	S			
1	а	k ₁	a ₁	a ₁			
2	n.c.	k ₂	a ₂	k ₂			
3	k	a ₁ , a ₂	k ₁ , k ₂	k ₁ , a ₂			

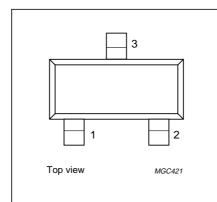


Fig.1 Simplified outline (SOT23) and pin configuration.

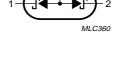


Fig.3 BAT721A diode configuration (symbol).

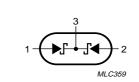


Fig.4 BAT721C diode configuration (symbol).

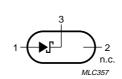


Fig.2 BAT721 single diode configuration (symbol).

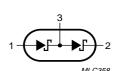


Fig.5 BAT721S diode configuration (symbol).

Schottky barrier (double) diodes

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		_	40	V
I _F	continuous forward current		_	200	mA
I _{FSM}	non-repetitive peak forward current	t _p = 8.3 ms half sinewave; JEDEC method	_	1	А
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	125	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	continuous forward voltage	see Fig.6			
		I _F = 10 mA	_	300	mV
		I _F = 100 mA	_	420	mV
		I _F = 200 mA	_	550	mV
I _R	continuous reverse current	V _R = 30 V; see Fig.7	_	15	μΑ
		$V_R = 30 \text{ V}; T_j = 100 ^{\circ}\text{C}; \text{ see Fig.7}$	_	3	mA
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.8	40	50	pF

Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

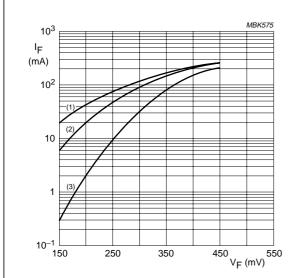
Note

1. Refer to SOT23 standard mounting conditions.

Schottky barrier (double) diodes

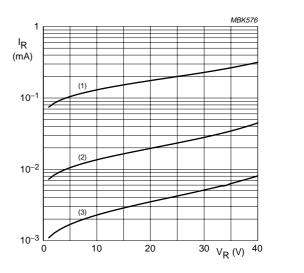
BAT721 series

GRAPHICAL DATA



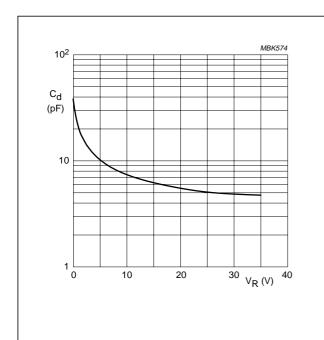
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.6 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.7 Reverse current as a function of reverse voltage; typical values.



f = 1 MHz; $T_j = 25 \,^{\circ}\text{C}$.

Fig.8 Diode capacitance as a function of reverse voltage; typical values.

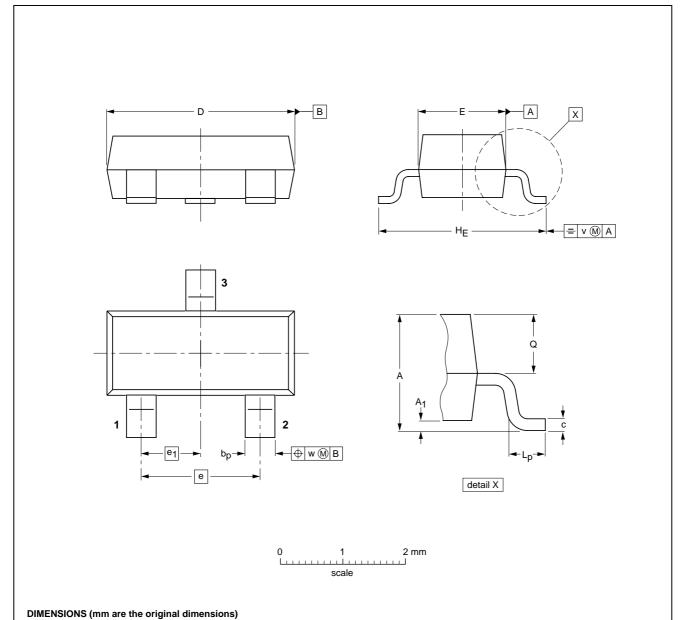
Schottky barrier (double) diodes

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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



UNIT	Α	max.	bp	С	D	E	е	e ₁	HE	L _p	Q	v	w	
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1	

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EDEC EIAJ PROJECTION		ISSUE DATE	
SOT23		TO-236AB				-97-02-28- 99-09-13

Schottky barrier (double) diodes

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

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NOTES

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